July 2009



FGI40N60SF 600V, 40A Field Stop IGBT

Features

- · High current capability
- Low saturation voltage: $V_{CE(sat)} = 2.3V @ I_C = 40A$
- High input impedance
- Fast switching •
- RoHS compliant •

Applications

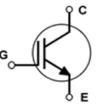
· Induction Heating, UPS, SMPS, PFC



General Description

Using Novel Field Stop IGBT Technology, Fairchild's new sesries of Field Stop IGBTs offer the optimum performance for Induction Heating, UPS, SMPS and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

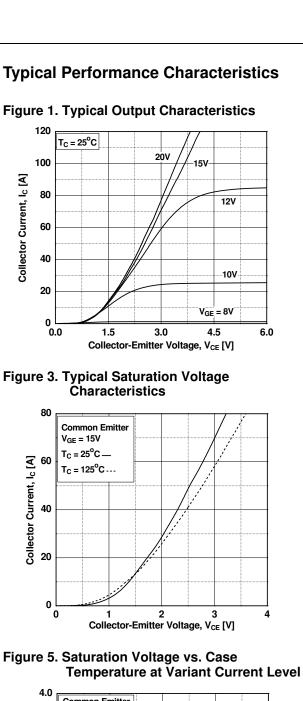
| Symbol | Description | | Ratings | Units | |
|---------------------|--|--------------------------|-------------|-------|--|
| V _{CES} | Collector to Emitter Voltage | | 600 | V | |
| V _{GES} | Gate to Emitter Voltage | | ± 20 | V | |
| ۱ _C | Collector Current | @ T _C = 25°C | 80 | A | |
| | Collector Current | @ T _C = 100°C | 40 | A | |
| I _{CM (1)} | Pulsed Collector Current | @ T _C = 25°C | 120 | A | |
| P _D | Maximum Power Dissipation | @ T _C = 25°C | 290 | W | |
| | Maximum Power Dissipation | @ T _C = 100°C | 116 | W | |
| TJ | Operating Junction Temperature | | -55 to +150 | °C | |
| T _{stg} | Storage Temperature Range | | -55 to +150 | °C | |
| TL | Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds | | 300 | °C | |

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Тур. | Max. | Units |
|-----------------------|---|------|------|-------|
| $R_{\theta JC}(IGBT)$ | Thermal Resistance, Junction to Case | - | 0.43 | °C/W |
| R_{\thetaJA} | Thermal Resistance, Junction to Ambient | - | 62.5 | °C/W |

| Device Marking FGI40N60SF | | Device P | Packaging ackage Type | Qty per Tube | | Max Qty per Box | | |
|-----------------------------------|--------------------------|--------------------------------------|---|--|------------------------|--------------------|------|----------|
| | | FGI40N60SFTU | TO262 Tube | | | | | |
| | | | | | | | | |
| | al Char | acteristics of the I | - | | NØ ¹ | T | | |
| Symbol | | Parameter | lest | Conditions | Min. | Тур. | Max. | Units |
| Off Charac | teristics | | | | | | | |
| BV _{CES} | Collector t | o Emitter Breakdown Voltage | $V_{GE} = 0V, I_{C}$ | ; = 250μA | 600 | - | - | V |
| ΔBV_{CES} ΔT_J | Temperati Voltage | ure Coefficient of Breakdown | $V_{GE} = 0V, I_{C} = 250\mu A$ | | - | 0.6 | - | V/ºC |
| I _{CES} | Collector | Cut-Off Current | $V_{CE} = V_{CES}, V_{GE} = 0V$ | | - | - | 250 | μA |
| I _{GES} | G-E Leak | age Current | $V_{GE} = V_{GES}, V_{CE} = 0V$ | | - | - | ±400 | nA |
| On Charac | torictics | | | | | 1 | | |
| V _{GE(th)} | 1 | shold Voltage | I _C = 250μA, | V _{CE} = V _{GE} | 4.0 | 5.0 | 6.5 | V |
| | | I _C = 40A, V _G | | - | 2.3 | 2.9 | V | |
| V _{CE(sat)} | Collector | to Emitter Saturation Voltage | $I_{\rm C}$ = 40A, $V_{\rm GE}$ = 15V, $T_{\rm C}$ = 125°C | | - | 2.5 | - | v |
| Dynamic C | haracteris | tics | | | - | | | ļ |
| C _{ies} | | nput Capacitance | | | - | 2110 | - | pF |
| C _{oes} | Output Ca | apacitance | V _{CE} = 30V, V _{GE} = 0V, f = 1MHz | | - | 200 | - | pF |
| C _{res} | Reverse 1 | Fransfer Capacitance | | | - | 60 | - | pF |
| | | | 1 | | 1 | 1 | | |
| Switching | 1 | | 1 | | - | 25 | | |
| t _{d(on)} | Rise Time | Delay Time | - | | - | 25 42 | - | ns |
| t _r | | Delay Time | 1001/1 404 | | - | 115 | - | ns |
| t _{d(off)} | Fall Time | | | $V_{CC} = 400V, I_C = 40A,$ $R_G = 10\Omega, V_{GE} = 15V,$ | | 27 | 54 | ns ns |
| t _f E _{on} | | Switching Loss | Inductive Load, $T_C = 25^{\circ}C$ | | - | 1.13 | - | mJ |
| E _{off} | | Switching Loss | + | | - | 0.31 | | mJ |
| E _{ts} | | ching Loss | | | - | 1.44 | _ | mJ |
| t _{d(on)} | | Delay Time | | | - | 24 | - | ns |
| t _r | Rise Time | , | 1 | | - | 43 | - | ns |
| t _{d(off)} | | Delay Time | V _{CC} = 400V, | $l_{c} = 40A$. | - | 120 | - | ns |
| t _f | Fall Time | · | R _G = 10Ω, V | ′ _{GE} = 15V, | - | 30 | - | ns |
| E _{on} | Turn-On S | Switching Loss | Inductive Load, T _C = 125°C | - | 1.14 | - | mJ | |
| E _{off} | | Switching Loss | 1 | | - | 0.48 | - | mJ |
| E _{ts} | Total Swit | ching Loss | 1 | | - | 1.62 | - | mJ |
| Qg | Total Gate | e Charge | | | - | 120 | - | nC |
| Q _{ge} | Gate to E | mitter Charge | $V_{CE} = 400V,$ | I _C = 40A, | - | 14 | - | nC |
| ~ | Gate to Collector Charge | | V _{GE} = 15V | | 1 | 58 | | nC |



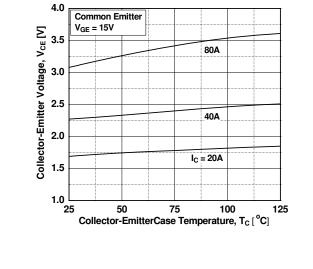


Figure 2. Typical Output Characteristics

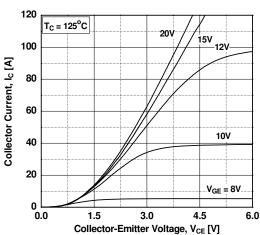


Figure 4. Transfer Characteristics

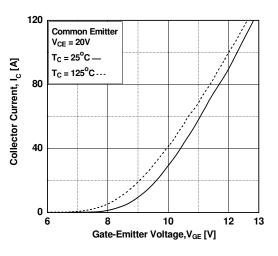
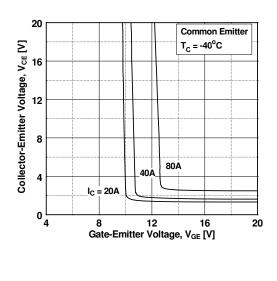
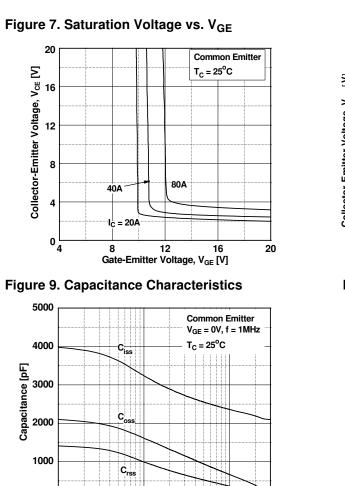


Figure 6. Saturation Voltage vs. $\rm V_{GE}$

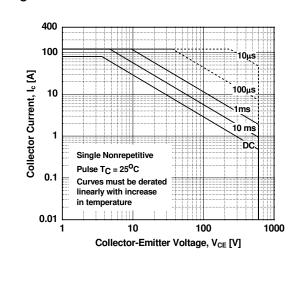




Typical Performance Characteristics

Figure 11. SOA Characteristics

0 └ 0.1



1 Collector-Emitter Voltage, V_{CE} [V]

Figure 8. Saturation Voltage vs. V_{GE}

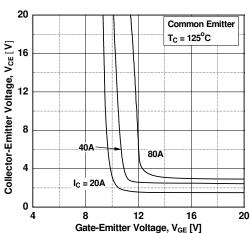


Figure 10. Gate charge Characteristics

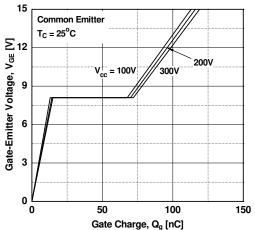
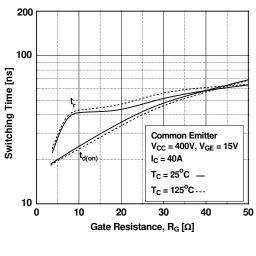
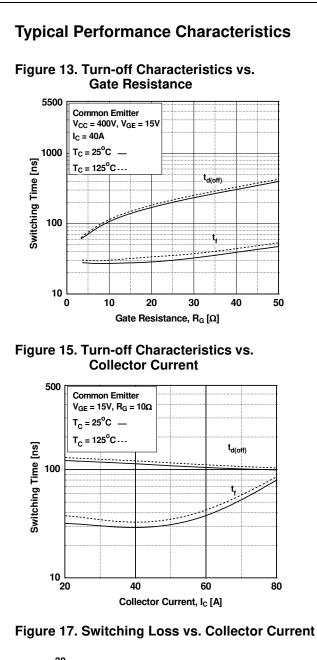


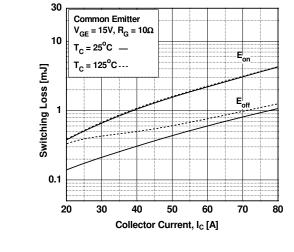
Figure 12. Turn-on Characteristics vs. **Gate Resistance**



30

10





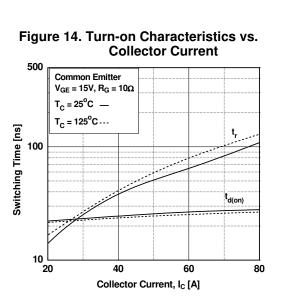


Figure 16. Switching Loss vs. Gate Resistance

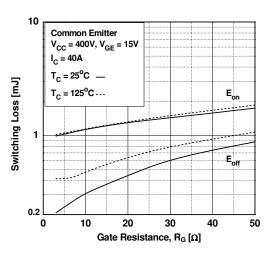
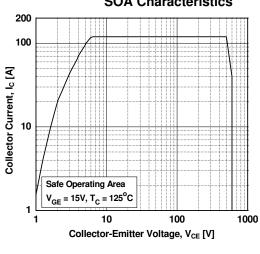
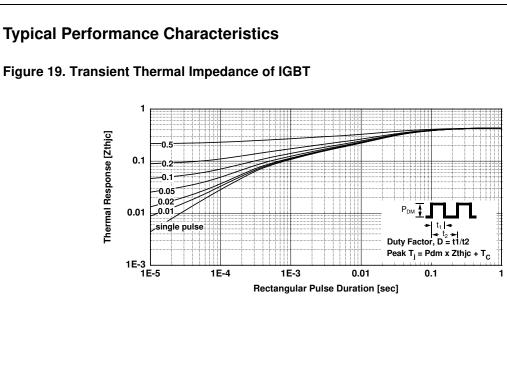
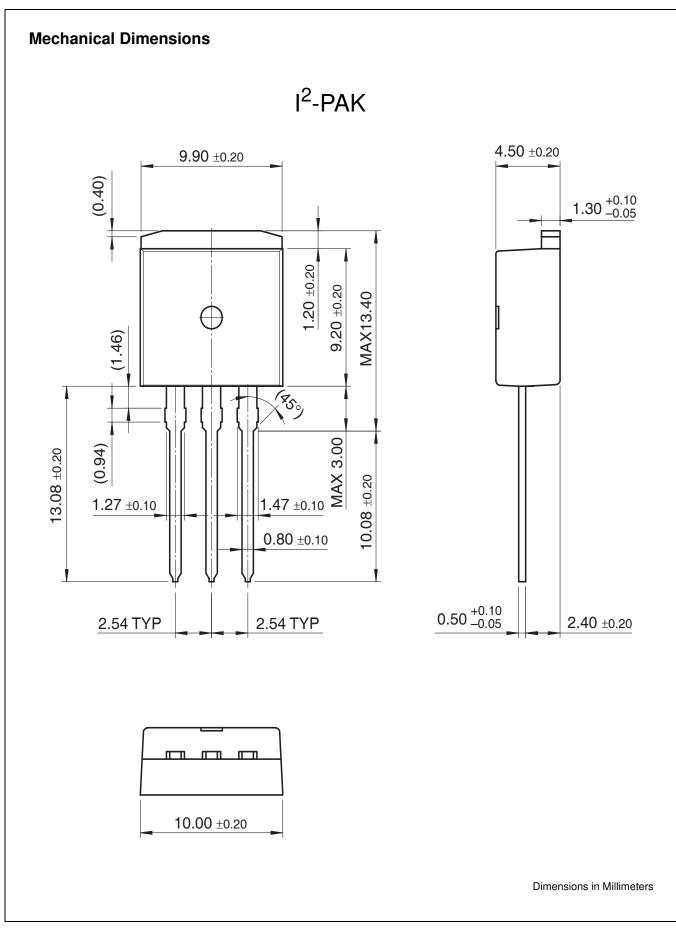


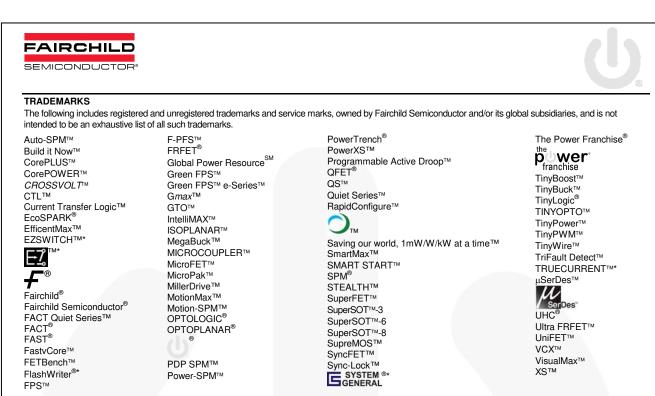
Figure 18. Turn off Switching SOA Characteristics



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